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#### FAIRCHILD

SEMICONDUCTOR

### 74ALVC16501

## Low Voltage 18-Bit Universal Bus Transceivers with 3.6V Tolerant Inputs and Outputs

#### **General Description**

The ALVC16501 is an 18-bit universal bus transceiver which combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in <u>each</u> direction is controlled by output-enable (OEAB and OEBA), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a HIGH or LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the LOW-to-HIGH transition of CLKAB. When OEAB is HIGH, the outputs are active. When OEAB is LOW, the outputs are in a highimpedance state.

<u>Data flow for B to A is similar to that of A to B but uses</u> OEBA, LEBA, and CLKBA. The output enables are complementary (OEAB is active HIGH and  $\overline{OEBA}$  is active LOW).

The ALVC16501 is designed for low voltage (1.65V to 3.6V)  $V_{CC}$  applications with I/O capability up to 3.6V.

The ALVC16501 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

#### Features

- 1.65V–3.6V V<sub>CC</sub> supply operation
- 3.6V tolerant inputs and outputs
- t<sub>PD</sub> (A to B, B to A)
  3.4 ns max for 3.0V to 3.6V V<sub>CC</sub>
  4.0 ns max for 2.3V to 2.7V V<sub>CC</sub>
  - 7.0 ns max for 1.65V to 1.95V  $V_{CC}$
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Uses patented noise/EMI reduction circuitry
- Latchup conforms to JEDEC JED78

ESD performance:

Human body model > 2000V Machine model >200V

Note 1: To ensure the high-impedance state during power up or power down,  $\overline{OEBA}$  should be tied to  $V_{CC}$  through a pull-up resistor and OEAB should be tied to GND through a pull-down resistor; the minimum value of the resistors is determined by the current-sourcing capability of the driver.

#### **Ordering Code:**

74ALVC16501MTD      MTD56      56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm        Devices also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.      Second Se	Wide
Devices also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.	

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#### **Connection Diagram**

		· · ·		
ОЕАВ —	1	$\bigcirc$	56	- GND
LEAB —	2		55	— CLKAB
A <sub>1</sub> —	3		54	— в <sub>1</sub>
GND —	4		53	- GND
A <sub>2</sub> —	5		52	— B <sub>2</sub>
A3 —	6		51	— B <sub>3</sub>
v <sub>cc</sub> –	7		50	– v <sub>cc</sub>
Α4 —	8		49	— В4
A <sub>5</sub> —	9		48	— B <sub>5</sub>
A <sub>6</sub> —	10		47	— B <sub>6</sub>
GND —	11		46	- GND
A <sub>7</sub> —	12		45	— B <sub>7</sub>
A <sub>8</sub> —	13		44	— B <sub>8</sub>
Ag —	14		43	— B <sub>9</sub>
A <sub>10</sub> —	15		42	— B <sub>10</sub>
A <sub>11</sub> —	16		41	— B <sub>1 1</sub>
A <sub>12</sub> —	17		40	— B <sub>12</sub>
GND —	18		39	- GND
A <sub>1.3</sub> —	19		38	— B <sub>13</sub>
A <sub>14</sub> —	20		37	— В <sub>14</sub>
A <sub>15</sub> —	21		36	— B <sub>15</sub>
v <sub>cc</sub> —	22		35	— ν <sub>cc</sub>
A <sub>16</sub> —	23		34	— В <sub>16</sub>
A <sub>17</sub> —	24		33	— В <sub>17</sub>
GND —	25		32	- GND
A <sub>18</sub>	26		31	- B <sub>18</sub>
OEBA -	27		30	- CLKBA
LEBA —	28		29	- GND
				1

#### **Pin Descriptions**

Pin Names	Description
OEAB	Output Enable Input for A to B Direction (Active HIGH)
OEBA	Output Enable Input for B to A Direction (Active LOW)
LEAB, LEBA	Latch Enable Inputs
CLKAB, CLKBA	Clock Inputs
A <sub>1</sub> -A <sub>18</sub>	Side A Inputs or 3-STATE Outputs
B <sub>1</sub> -B <sub>18</sub>	Side B Inputs or 3-STATE Outputs

#### Function Table (Note 2)

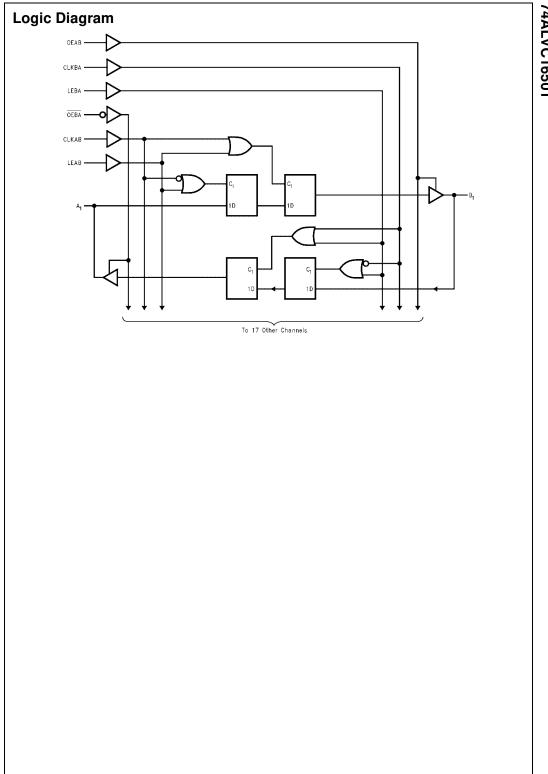
	Ing		Outputs	
OEAB	LEAB	CLKAB	A <sub>n</sub>	B <sub>n</sub>
L	Х	х	Х	Z
н	н	х	L	L
н	н	х	н	н
Н	L	$\uparrow$	L	L
н	L	$\uparrow$	н	н
Н	L	Н	х	B <sub>0</sub> (Note 3)
н	L	L	Х	B <sub>0</sub> (Note 4)

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial (HIGH or LOW, inputs may not float) Z = High Impedance

Note 2: A to-B data flow is shown; B-to-A flow is similar but uses  $\overline{\text{OEBA}}$ , LEBA and CLKBA.  $\overline{\text{OEBA}}$  is active LOW.

Note 3: Output level before the indicated steady-state input conditions were established.

Note 4: Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.



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#### Absolute Maximum Ratings(Note 5)

Supply Voltage (V <sub>CC</sub> )	-0.5V to +4.6V
DC Input Voltage (VI)	-0.5V to 4.6V
Output Voltage (V <sub>O</sub> ) (Note 6)	–0.5V to V <sub>CC</sub> +0.5V
DC Input Diode Current (IIK)	
V <sub>1</sub> < 0V	–50 mA
DC Output Diode Current (I <sub>OK</sub> )	
V <sub>O</sub> < 0V	–50 mA
DC Output Source/Sink Current	
(I <sub>OH</sub> /I <sub>OL</sub> )	±50 mA
DC V <sub>CC</sub> or GND Current per	
Supply Pin (I <sub>CC</sub> or GND)	±100 mA
Storage Temperature Range $(T_{STG})$	$-65^{\circ}C$ to $+150^{\circ}C$

#### **Recommended Operating**

Conditions (Note 7)

Power Supply	
Operating	1.65V to 3.6V
Input Voltage (V <sub>I</sub> )	0V to $V_{CC}$
Output Voltage (V <sub>O</sub> )	0V to $V_{CC}$
Free Air Operating Temperature (T <sub>A</sub> )	$-40^{\circ}C$ to $+85^{\circ}C$
Minimum Input Edge Rate ( $\Delta t/\Delta V$ )	
$V_{IN} = 0.8V$ to 2.0V, $V_{CC} = 3.0V$	10 ns/V

Note 5: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 6: I<sub>O</sub> Absolute Maximum Rating must be observed.

Note 7: Floating or unused inputs must be held HIGH or LOW.

#### **DC Electrical Characteristics**

Symbol Parameter				Min	Max	Units	
VIH	HIGH Level Input Voltage		1.65 -1.95	$0.65 \times V_{CC}$			
			2.3 - 2.7	1.7		V	
			2.7 - 3.6	2.0			
VIL	LOW Level Input Voltage		1.65 -1.95		$0.35 \times V_{CC}$		
			2.3 - 2.7		0.7	V	
			2.7 - 3.6		0.8		
V <sub>OH</sub>	HIGH Level Output Voltage	I <sub>OH</sub> = -100 μA	1.65 - 3.6	V <sub>CC</sub> - 0.2			
		$I_{OH} = -4 \text{ mA}$	1.65	1.2			
		$I_{OH} = -6 \text{ mA}$	2.3	2			
		$I_{OH} = -12 \text{ mA}$	2.3	1.7		V	
			2.7	2.2			
			3.0	2.4			
		$I_{OH} = -24 \text{ mA}$	3.0	2			
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	1.65 - 3.6		0.2		
		$I_{OL} = 4 \text{ mA}$	1.65		0.45		
		I <sub>OL</sub> = 6 mA	2.3		0.4	v	
		I <sub>OL</sub> = 12mA	2.3		0.7	v	
			2.7		0.4		
		I <sub>OL</sub> = 24 mA	3		0.55		
l <sub>l</sub>	Input Leakage Current	$0 \le V_I \le 3.6V$	3.6		±5.0	μA	
I <sub>OZ</sub>	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	3.6		±10	μA	
I <sub>CC</sub>	Quiescent Supply Current	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6		40	μA	
Δl <sub>CC</sub>	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6V$	3 -3.6		750	μA	

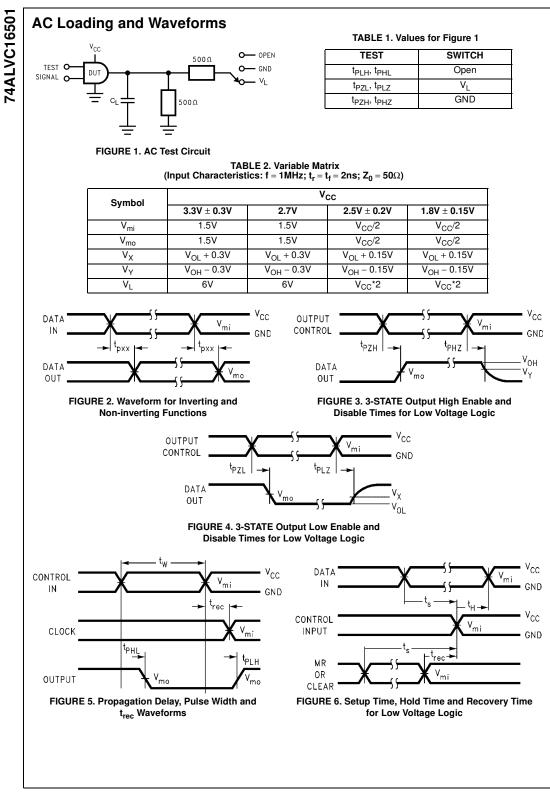
#### **AC Electrical Characteristics**

Symbol		T <sub>A</sub> = $-40^{\circ}$ C to $+85^{\circ}$ C, R <sub>L</sub> = $500\Omega$								
	Parameter	C <sub>L</sub> = 50 pF			C <sub>L</sub> = 30 pF				Units	
		V $_{CC}$ = 3.3V $\pm$ 0.3V		$V_{CC} = 2.7V$		V $_{CC}$ = 2.5V $\pm$ 0.2V		V $_{CC}$ = 1.8V $\pm$ 0.15V		onits
		Min	Max	Min	Max	Min	Max	Min	Max	1
f <sub>MAX</sub>	Maximum Clock Frequency	250		200		200		100		ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay Bus to Bus	1.1	3.4	1.3	4.0	0.8	3.5	1.5	7.0	ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay CLK to Bus	1.1	4.0	1.3	4.9	0.8	4.4	1.5	8.8	ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay LE to Bus	1.1	4.3	1.3	5.4	0.8	4.9	1.5	9.8	ns
t <sub>PZL</sub> , t <sub>PZH</sub>	Output Enable Time	1.1	4.3	1.3	5.4	0.8	4.9	1.5	9.8	ns
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Output Disable Time	1.3	4.2	1.3	4.7	0.8	4.2	0.8	7.6	ns
tw	Pulse Width	1.5		1.5		1.5		4.0		ns
ts	Setup Time	1.5		1.5		1.5		2.5		ns
t <sub>H</sub>	Hold Time	1.0		1.0		1.0		1.0		ns

#### Capacitance

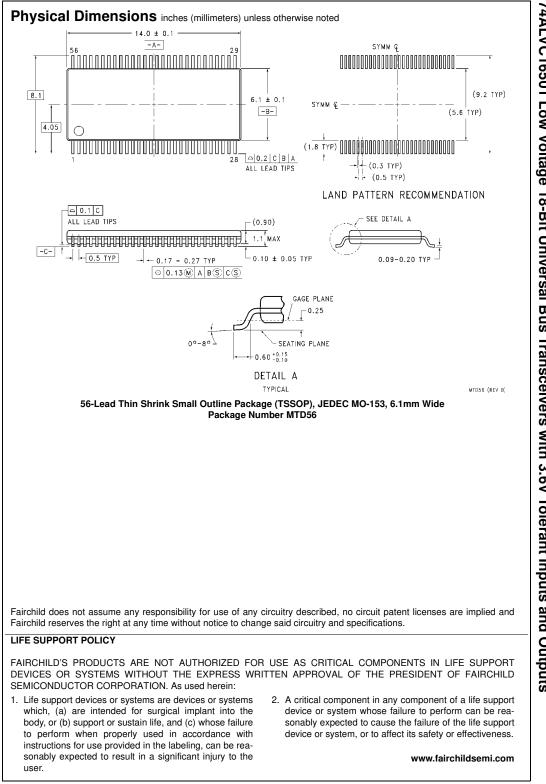
Symbol	Parameter		Conditions	<b>TA</b> = -	Units	
	Faidilielei		Conditions	V <sub>cc</sub>	Typical	Units
CIN	Input Capacitance		$V_I = 0V \text{ or } V_{CC}$	3.3	6	pF
C <sub>OUT</sub>	Output Capacitance		$V_I = 0V \text{ or } V_{CC}$	3.3	7	pF
C <sub>PD</sub>	Power Dissipation Capacitance C	Outputs Enabled	f = 10 MHz, C <sub>L</sub> = 50 pF	3.3	20	рF
				2.5	20	PΓ

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